

Green Products

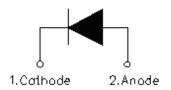
MBRF1060 SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- **Reverse battery protection**
- Center tap configuration

Features:

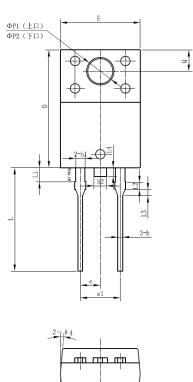
- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Pure tin plated, solderable per MIL-STD-750, Method 2026
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

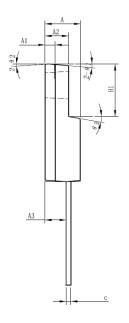


TYP.

MAX

Mechanical Dimensions: In mm





2-	0 4		
	фп		
1	0.5		

STWIBOL	IVIIIN.	IIF.	IVIAA.
Α	4.30	4.50	4.70
A1 A2 A3 b	1.10	1.30 3.00 2.70 0.60 1.20	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	2.80 2.50 0.50 1.10	1.20	3.20 2.90 0.75 1.35
b2	1.50	1.60	1./5
С	0.55	0.60	0.75
C D E e	14.80	15.00	15.20
E	9.96	10.16	10.36
е	•	10.16 2.55 5.10 6.70 13.20 1.80 1.00 0.80	-
e1	-	5.10	-
H1	6.50	6.70	6.90
	12.70	13.20	13.70
L1	1.60	1.80	2.00
L1 L2 L3	0.80	1.00	1.20
L3	0.60	0.80	1.00
L4	-	1.10	1.50
ФР1(上口)	3.30	3.50	13.70 2.00 1.20 1.00 1.50 3.70
ΦP2(下口)	2.99	3.19	3.39
Q	2.50	1.10 3.50 3.19 2.70	2.90
Θ1		L E0	
Θ2		4° 10° 5°	
Θ3 Θ4		10°	
Θ4		5°	
Θ5		5°	

MIN

SYMBOL

ITO-220AC(HD)

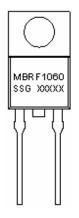
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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Where XXXXX is YYWWL

MBR = Device Type F = Package type

10 = Forward Current (10A) 60 = Reverse Voltage (60V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Ordering Information:

Device	Package	Shipping
MBRF1060	ITO-220AC (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	60	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C = 80°C, rectangular wave form	10	Α
Peak One Cycle Non-Repetitive Surge Current(per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	Α

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 10A, Pulse, T _J = 25 °C	0.66	0.80	V
	V_{F2}	@ 10A, Pulse, T _J = 125 °C	0.61	0.70	V
Reverse Current*	I _{R1}	@V _R = rated V _R	0.009	1.0	mA
		T _J = 25 °C			
	I_{R2}	@V _R = rated V _R	3	6	mA
		T _J = 125 °C			
Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 °C$	260	400	pF
		f _{SIG} = 1MHz			
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	2.0	°C/W
Typical Thermal Resistance, Case to Heat Sink	$R_{ heta CS}$	Mouting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	1.6	g
Case Style		ITO-220AC		



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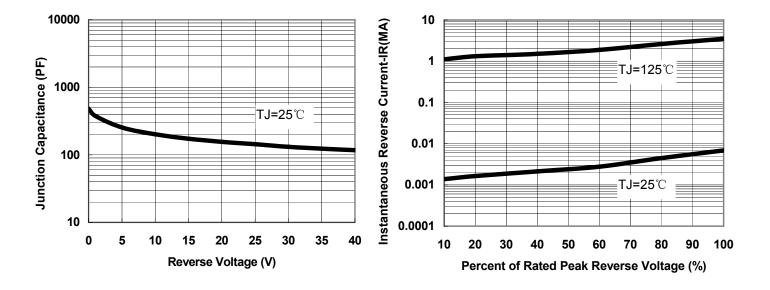


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

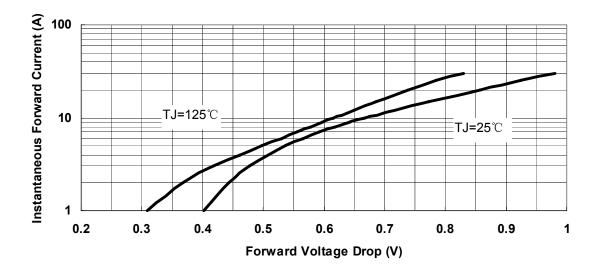


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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